Project reference : PTDC/FIS/121383/2010						Primary Irradiation				Secondary Irradiation	
Project title: Luminescence Analysis of Radiation Effects - LARE Prefix For				or Signal	Photo-	Cathodo-	Radio-	Iono-	Thermally Stimulated-	Photon/Optically Stimulated-	
Luminescence and related signals in LARE Matrix of compatible irradiation and detection regimes					Туре	Photon beam/radiation	Low energy accelerated electron	Ionising radiation: X; γ; β/high energy accelerated electron; α	Ion beam: accelerated ion ranging in mass from proton to heavy charged particle	Thermodynamic eviction of charge from traps filled during primary irradiation	Electromagnetic eviction of charge from traps filled during primary irradiation
Detection				Irradi	Energy	Theory: any including ionising. Practice: generally MidIR-UV: 10^{-2} - 10^2 eV	10^{0} - 10^{3} eV	$10^3 - 10^7 \text{ eV}$	$10^3 - 10^7 \text{ eV}$	Limits defined by coolant (LN_2) and incandescence (77-1000 K): $10^{-3}-10^{-1}$ eV	Theory: any including ionising. Practice: generally NIR-UV: 10^{-1} - 10^2 eV
Signal	Precursor Process	Emission Process	Туре	Timescale	Measur ement	1	2	3	4	5	6
Raman Scattering	Transfer of energy from photons to molecular electronic energy states	Vibrational relaxation	Photon	10 ⁻¹² s	А	During Irradiation, mainly Stokes	-	-	-	-	During Irradiation
Fluor- escence	Excitation of electrons in atoms/molecules by resonance	De-exitation	Photon	10 ⁻⁹ s	В	During Irradiation (& after ps pulse), mainly Stokes	During Irradiation	During Irradiation	During Irradiation	During Irradiation	During Irradiation (& after ps pulse), use Anti-Stokes
Phosphor- escence	Exitation of electrons in, or ionisation of, atoms/molecules	Delayed de- exitation (quantum state change) and/or trapping and recombination	Photon	10 ⁻³ + s	С	During / After Irradiation, mainly Stokes	During / After Irradiation	During / After Irradiation	During / After Irradiation	During / After Irradiation	During / After Irradiation use Anti-Stokes
Conductivity	Ionisation of atoms/molecules or eviction of charge from traps	Presence of charge in conduction band	Reduced electrical resistance	10 ⁻³ -10 ² s during Phosphor- esence	D	Little unless photoelectric threshold acheived	During / After Irradiation	During / After Irradiation	During / After Irradiation	During / After Irradiation	During / After Irradiation
Exo-electron emission	Thermal or electromagnetic stimulation of near- surface electrons, already in the conduction band or directly from traps	Energy exceeds work function of the material or a local defect structure	Electron (current)	10^{-9} - 10^2 s	Е	Little unless photoelectric threshold acheived	-	During / After Irradiation	During / After Irradiation	During / After Irradiation	During / After Irradiation